

B L GALAXY ELECTRICAL

BYW95A(Z)---BYW95C(Z)

FAST RECOVERY RECTIFIER

VOLTAGE RANGE: 200 --- 600 V
CURRENT: 3.0 A

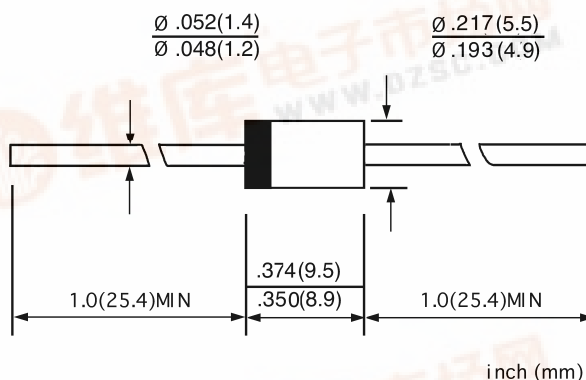
FEATURES

- ◇ Low cost
- ◇ Diffused junction
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with Freon, Alcohol, Isopropanol and similar solvents
- ◇ The plastic material carries U/L recognition 94V-0

MECHANICAL DATA

- ◇ Case: JEDEC DO-27, molded plastic
- ◇ Terminals: Axial lead, solderable per MIL-STD-202, Method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.041 ounces, 1.15 grams
- ◇ Mounting position: Any

DO - 27



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		BYW95A	BYW95B	BYW95C	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	200	400	600	V
Maximum RMS voltage	V_{RMS}	140	280	420	V
Maximum DC blocking voltage	V_{DC}	200	400	600	V
Maximum average forward rectified current 9.5mm lead length, @ $T_A=75^\circ\text{C}$	$I_{F(AV)}$	3.0			A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load @ $T_J=125^\circ\text{C}$	I_{FSM}	70.0			A
Maximum instantaneous forward voltage @ 3.0 A	V_F	1.5			V
Maximum reverse current @ $T_A=25^\circ\text{C}$ at rated DC blocking voltage @ $T_A=100^\circ\text{C}$	I_R	10.0 100.0			μA
Maximum reverse recovery time (Note1)	t_{rr}	250			ns
Typical junction capacitance (Note2)	C_J	32			pF
Typical thermal resistance (Note3)	$R_{\theta JA}$	22			$^\circ\text{C/W}$
Operating junction temperature range	T_J	-55-----+150			$^\circ\text{C}$
Storage temperature range	T_{STG}	-55-----+150			$^\circ\text{C}$

NOTE: 1. Measured with $I_F=0.5\text{A}$, $I_R=1\text{A}$, $t_r=0.25\text{A}$.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance from junction to ambient.

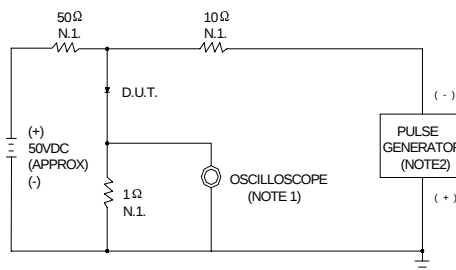
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RATINGS AND CHARACTERISTIC CURVES

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FIG.1 – REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



NOTES: 1. RISE TIME= 7ns MAX. INPUT IMPEDANCE= 1MΩ, 22PF
2. RISE TIME= 10ns MAX. SOURCE IMPEDANCE= 50Ω

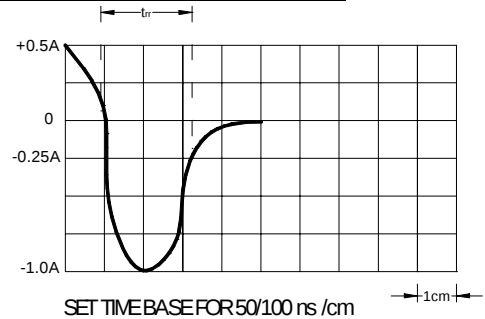
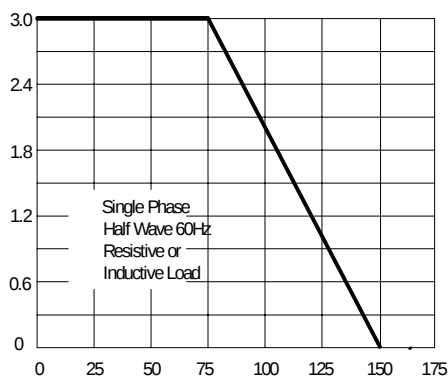


FIG.2 –FORWARD DERATING CURRENT

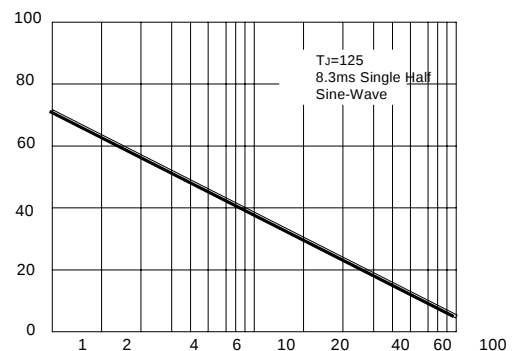
AVERAGE FORWARD RECTIFIED CURRENT
AMPERES



AMBIENT TEMPERATURE, °C

FIG.3 –PEAK FORWARD SURGE CURRENT

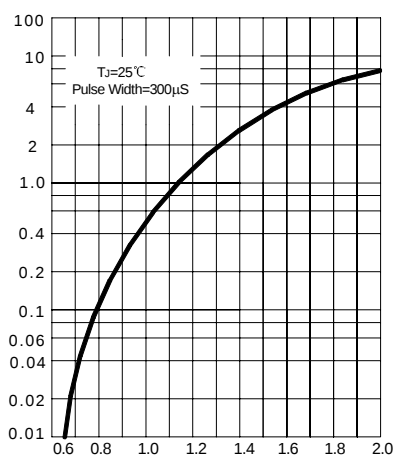
PEAK FORWARD SURGE CURRENT
AMPERES



NUMBER OF CYCLES AT 60 Hz

FIG.4-TYPICAL FORWARD CHARACTERISTIC

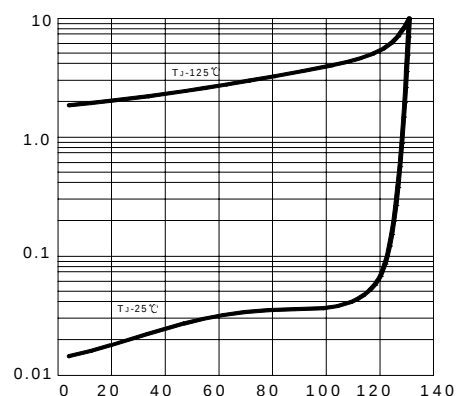
INSTANTANEOUS FORWARD CURRENT
AMPERES



INSTANTANEOUS FORWARD VOLTAGE, VOLTS

FIG.5-TYPICAL REVERSE CHARACTERISTICS

REVERSE CURRENT, MICROAMPERES



PERCENT OF RATED REVERSE VOLTAGE, %